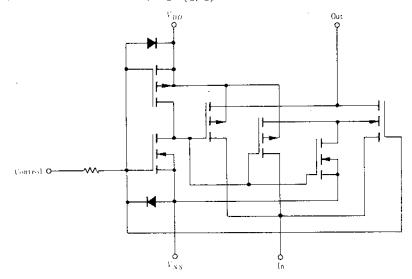
HD14016B

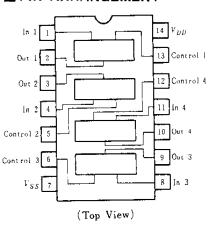
Quadruple Analog Switch/ Quadruple Multiplexer

The HD14016B quad bilateral switch consists of four independent switches capable of controlling either digital or analog signals. The quad bilateral switch is used in signal gating, chopper, modulator, demodulator and CMOS logic implementation.

■CIRCUIT SCHEMATIC (1/4)



PIN ARRANGEMENT



■ ELECTRICAL CHARACTERISTICS

Characteristic		Symbol	Test Circuit	Test Conditions			-40°C		25 ℃			85°C		Unit		
		Symbol		$V_{DD}(V)$	lest Conditions			min	max	min	typ	max	min	max		
				5.0	$R_L = 101$	sΩ	$V_0 = 1.0 \mathrm{V}$		0.9	_	1.5	0.9	_	0.9		
		VIL		10	SW Input		$V_o = 1.0 \mathrm{V}$	_	0.9		1.5	0.9	_	0.9	V	
Input Voltage			1	15	$=V_{DD}$	-	$V_o = 1.0 \text{ V}$		0.9	_	1.5	0.9	_	0.9		
		ViH		5.0	$R_L = 10$	kΩ	$V_o = 4.0 \mathrm{V}$	3.5		3.5	2.75		3.5			
				10	SW Inp	out Vo	$V_0 = 9.0 \mathrm{V}$	7.0	-	7.0	5.5	_	7.0	_	V	
				15	$=V_{DD}$		$V_o = 14 \text{ V}$	11.0	_	11.0	8.25	_	11.0			
Input Current		Iin.		15			,	-	±0.3	_	±0.00001	±0.3	_	±1.0	μΑ	
Input Capaci-	Control		<u> </u>	I I				5.0					-	_		
	Switch Input		!					_		_	5.0	_ i	_	-	_	
	Switch Output	Cin						_	_	_	5.0		_		pF	
	Feed Through	1		! :				_	_	_	0.2		-	_	1	
				5.0				-	1.0	_	0.0005	1.0	_	7.5		
Quiescent Current		IDD	2	10	-			_	2.0	_	0.0010	2.0	_	15	μΑ	
				15			4	_	4.0		0.0015	4.0	_	30	1	
		<u> </u>		5.0		Vss = -5 V	V _{in} = -5.0V	ļ	610	_	300	660		840))	
							$V V_{in} = -5.0V$		610	_	300	660	_	840		
							$V_{cr} = \pm 0.25$	r —	610		280	660		840		
			İ	7.5		$V_{SS} = -7.5$	V.n = -7.5V	T -	370	_	240	400	-	520		
							$5V V_{is} = -7.5V$	_	370		240	400	_	520		
		Ron			$V_C = V_{BB}$		$V_{cr} = \pm 0.25$	 	370	i –	180	400	_	520	Ω	
"ON" Re	esistance		3	10	$R_L = 10k\Omega$		V., = - 10V	-	610	-	260	660		840		
						Vss= 0 V	$V_{14} = -0.25$	7 -	610	_	260	660	_	840	•	
				15			V., = -5.6V		610	-	310	660		840	i	
						ļ 	$V_{\rm in} = +15 \text{V}$	-	370	† –	260	400		520	1	
						Vss = 0 V	$V_{r*} = +0.25^{\circ}$	7 -	370	-	260	400		520	•	
					İ		V. = +9.3V	 	370	_	300	400	_	520		
"ON" D		 		5.0	-	V.a =	± 5.0V, Vss= - 5 V	 		_	15		_			
"ON" Resistance Difference		△Ron		7.5	$V_C = V_{DD}$		±7.5V, Vss=-7.5	v	-	_	10	<u> </u>	_	_	l C	
		+	+	+	 	$V_{cs} = \pm 5.0$	$\overline{V_i} \ V_{out} = -5.0$	/ -	± 125	T -	±0.001	± 125				
Input/Output				5.0		·	$V_{\rm out} = +5.0^{\circ}$		±125	+	±0.001		_	_	-	
•	Current	ent			V _C = V _{ss}		$V_{\text{out}} = -7.5^{\circ}$		± 250	+	±0.0015	± 250		-	nA	
				7.5			$V_{\text{out}} = +7.5^{\circ}$		± 250	-	±0.0015	+	i –	_	ĺ	

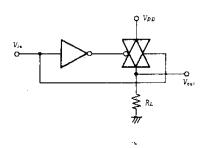


■ SWITCHING CHARACTERISTICS

Characteristic		Symbol	Test Circuit	VDD(V)	Test Conditions		min	typ	max	Unit	
		1		5.0			_	15	45		
Propagation Delay Time		tplh		10			_	7.0	15	ns	
	Data Input			15	V V P1010 V 0 V			6.0	12		
	Data Input	tphl	4	5.0	$V_C = V_{DD}$, $R_L = 10 k\Omega$, $V_{SS} = 0 \text{ V}$		_	15	45	ns	
				10				7.0	15		
				15			_	6.0	12		
		tplh tphl	5	5.0	V_{in} \leq $10\mathrm{V}$, R_L = $1.0\mathrm{k}\Omega$, V_{SS} = $0\mathrm{V}$		_	34	90	ns ns	
				10			_	20	45		
				15		N.		15	35		
	Control Input			5.0	$V_{in} \leq 10 \text{ V}, RL = 1.0 \text{ R} \Omega, V_{SS} = 0$	V	_	34	90		
				10			<u> </u>	20	45		
				15			_	15	35		
Crosstalk (Control to Output)			6	5.0	Vo - Vos - P - 1 01 0		_	30	_		
				10	$ \begin{array}{l} V_C = V_{DD}, R_{in} = 1.0 \text{k}\Omega, \\ \downarrow R_{in} = 10 \text{k}\Omega, V_{CG} = 0. \text{V} \end{array} $		-	50	_	mV	
				15	$R_{out} = 10 \mathrm{k}\Omega$, $V_{SS} = 0$ V			100	_	l	
Crosstalk (between any two switches)				5.0	$R_L=1.0 \text{k}\Omega$, $f=1.0 \text{MHz}$, $V_{SS}=0$ Crosstalk=20log10 V_{out} 1 / V_{out} 2	$L=1.0k\Omega$, $f=1.0MHz$, $V_{SS}=0$ V, rosstalk=20log10 V_{out} 1/ V_{out} 2		80	_	dB	
Maximum Control Input Pulse Frequency		-	5.0					5.0		:	
				10	$RL=1.0$ k Ω , V ss $=0$ V			10		MHz	
		!		15				12		;	
		ĺ		5.0			; —	24	_		
Noise Voltage		V _n	7	10	$V_C = V_{DD}$, $f = 100$ Hz, $V_{SS} = 0$ V	$= V_{DD}, f = 100 \text{Hz} V_{SS} = 0 \text{ V}$		25		nV/√ Hz	
				15	$V_C = V_{DD}$, $f = 100$ kHz, $V_S = 0$ V		_	30			
				5.0				12			
				10				12			
				15	10 122, 7 1000122, 133 0 7		15				
Sine Wave (Distortion)				5.0	$V_{in}=1.77 \text{ V (rms Centered } @0.09$ $RL=10\text{k}\Omega$, $f=1.0\text{kHz}$, $Vss=-$			0.16		······	
						T	<u> </u>	0.0	_		
Insertion Loss			5.0		$V_C = V_{DD}$, $V_{in} = 1.77 \text{V}$, $V_{SS} = -5 \text{ V}$.	$R_L = 1.0 \text{k}\Omega$	_	2.3		-	
				5.0	rms Centered @0.0V, $f=1MHz$,	$R_L = 10 \text{k}\Omega$	<u> </u>	0.2		dВ	
		ĺ			$I.L = 20\log 10 \frac{V_{out}}{V_{in}}$	$R_L = 100 \text{k}\Omega$: <u> </u>	0.1			
						$R_L = 1.0 \text{M}\Omega$		0.05	. –		
Bandwidth		BW	8	5.0	$V_{\rm C} = V_{\rm DD}$, $V_{\rm in} = 1.77 { m V}$,	$R_L=1.0k\Omega$		54			
					$V_{SS} = -5$ V, rms Centered	$R_L = 10 \text{k}\Omega$	<u> </u>	40		MHz	
					@ $0.0V$, $-3 dB$	$R_L = 100 \text{k}\Omega$		38			
		<u> </u>				$R_L = 1.0 \text{M}\Omega$	-	37		ļ	
Feedthrough				5.0	Vc = Vss, Vss = -5 V,	$R_L = 1.0 \text{k}\Omega$	_	1250		kHz	
						$RL = 10k\Omega$	_	140			
					$20\log 10 \frac{V_{out}}{V_{in}} = -50 \text{dB} \qquad \frac{RL = 100 \text{kB}}{R_L = 100 \text{kB}}$		_	18		- 	
				Ĺ		$R_L = 1.0 M\Omega$		2.0	-		

■DC CHARACTERISTIC TEST CIRCUIT

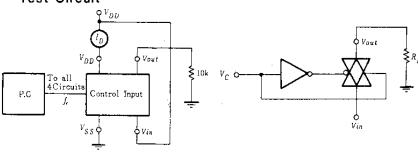
1. $V_{\rm IL}$, $V_{\rm IH}$



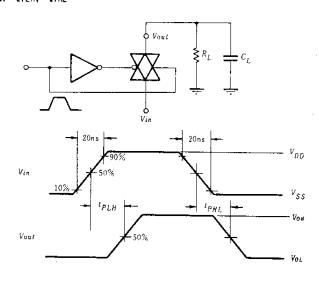
2. Quiescent Power Dissipation 3. Row

Test Circuit

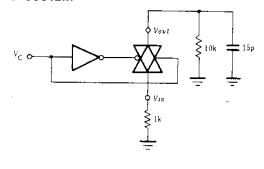
 $P_{\bar{U}} = V_{\bar{D}\bar{D}} \times I_{\bar{D}}$



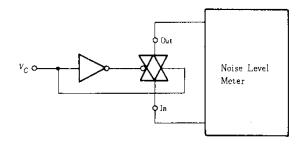
 $4,\ t_{\text{PLH}},\ t_{\text{PHL}}$



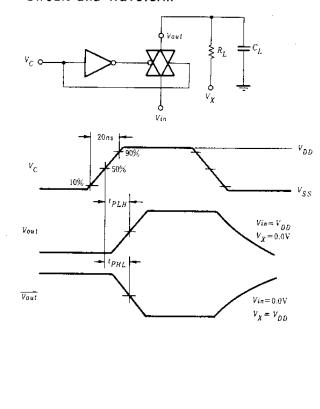
6. Crosstalk



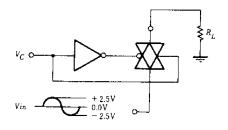
7. V.



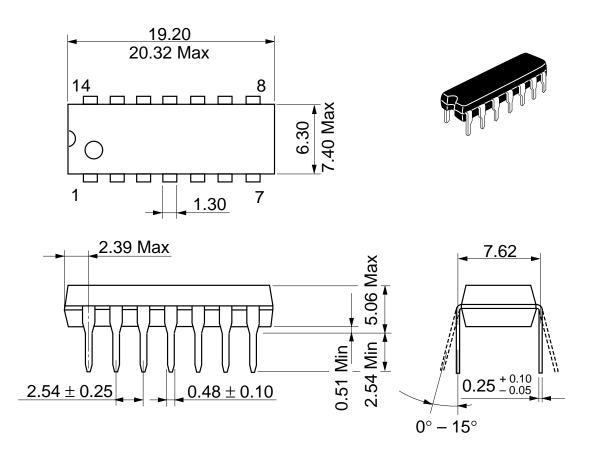
5. Turn-on Delay Time Test Circuit and Waveform



8. BW



Unit: mm



Hitachi Code	DP-14
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.97 g

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